

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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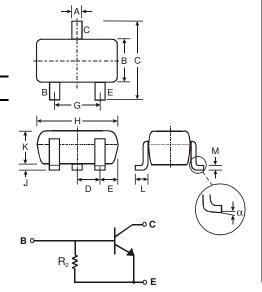
Features

- Epitaxial Planar Die Construction
- Complementary PNP Types Available (DDTA)
- · Built-In Biasing Resistor, R2 only
- Lead Free/RoHS Compliant (Note 2)
- "Green" Device (Note 3 and 4)

Mechanical Data

- Case: SOT-323
- Case Material: Molded Plastic, "Green" Molding Compound, Note 4. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminal Connections: See Diagram
- Terminals: Solderable per MIL-STD-202, Method 208
- Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe).
- Marking: Date Code and Type Code, See Page 3
- Ordering Information: See Page 3
- Type Code: See Table Below
- Weight: 0.006 grams (approximate)

P/N	R2 (NOM)	Type Code
DDTC114GUA	10ΚΩ	N26
DDTC124GUA	22ΚΩ	N27
DDTC144GUA	47ΚΩ	N28
DDTC115GUA	100KΩ	N29



SCHEMATI	C DIAC	GRAM

SOT-323								
Dim	Min	Max						
Α	0.25	0.40						
В	1.15	1.35						
С	2.00 2.20							
D	0.65 Nominal							
Е	0.30	0.40						
G	1.20	1.40						
Н	1.80	2.20						
J	0.0 0.10							
K	0.90	1.00						
L	0.25	0.40						
М	0.10	0.18						
α	0°	8°						
All Dimensions in mm								

Maximum Ratings @TA = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit		
Collector-Base Voltage	V _{CBO}	50	V		
Collector-Emitter Voltage	V _{CEO}	50	V		
Emitter-Base Voltage	V _{EBO}	5	V		
Collector Current	I _C (Max)	100	mA		
Power Dissipation	P _d	200	mW		
Thermal Resistance, Junction to Ambient Air (Note 1)	$R_{ heta JA}$	625	°C/W		
Operating and Storage Temperature Range	T _j , T _{STG}	-55 to +150	°C		

Notes:

- 1. Mounted on FR4 PC Board with recommended pad layout as shown on Diodes Inc., suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.
- 2. No purposefully added lead.
- 3. Diodes Inc.'s "Green" Policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.
- Product manufactured with date code 0627 (week 27, 2006) and newer are built with Green Molding Compound. Product manufactured prior to date code 0627 are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.

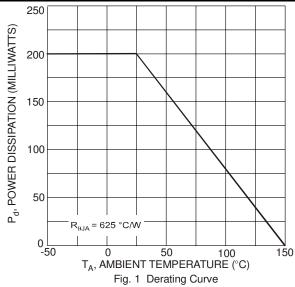


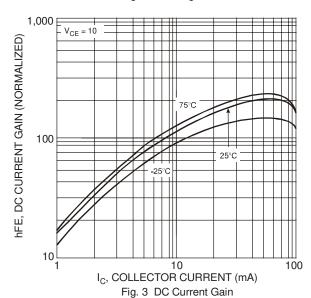
Electrical Characteristics @T_A = 25°C unless otherwise specified

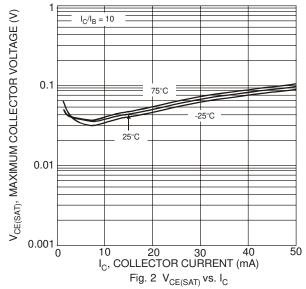
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
Collector-Base Breakdown Voltage	ollector-Base Breakdown Voltage		50	_	_	V	$I_C = 50\mu A$
Collector-Emitter Breakdown Voltage	!	BV _{CEO}	50	_	_	V	$I_C = 1mA$
Emitter-Base Breakdown Voltage		BV _{EBO}	5		_	٧	I_E = 720μA, DDTC114GUA I_E = 330μA, DDTC124GUA I_E = 160μA, DDTC144GUA I_E = 72μA, DDTC115GUA
Collector Cutoff Current		I_{CBO}			0.5	μΑ	$V_{CB} = 50V$
Emitter Cutoff Current	DDTC114GUA DDTC124GUA DDTC144GUA DDTC115GUA	I _{EBO}	300 140 65 30		580 260 130 58	μА	V _{EB} = 4V
Collector-Emitter Saturation Voltage		V _{CE(sat)}			0.3	>	$I_C = 10mA, I_B = 0.5mA$
DDTC114GUA DC Current Transfer Ratio DDTC124GUA DDTC124GUA DDTC144GUA DDTC115GUA		h _{FE}	30 56 68 82			l	$I_C = 5mA$, $V_{CE} = 5V$
Bleeder Resistor (R ₂) Tolerance		ΔR_2	-30	_	+30	%	
Gain-Bandwidth Product*		f _T	_	250	_	MHz	$V_{CE} = 10V, I_{E} = -5mA,$ f = 100MHz

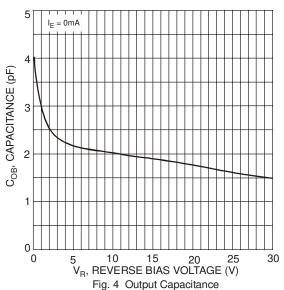
^{*} Transistor - For Reference Only

Typical Characteristics - DDTC114GUA

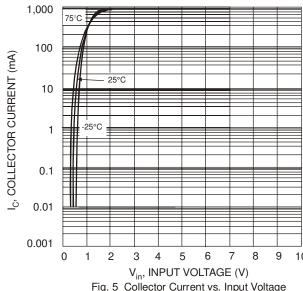












10 $V_{O} = 0.2$ Vin, INPUT VOLTAGE (V) 200 100 300 400 600 700 500 I_C, COLLECTOR CURRENT (mA) Fig. 6 Input Voltage vs. Collector Current

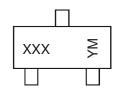
Fig. 5 Collector Current vs. Input Voltage

Ordering Information (Note 4 & 5)

Device	Packaging	Shipping
DDTC114GUA-7-F	SOT-323	3000/Tape & Reel
DDTC124GUA-7-F	SOT-323	3000/Tape & Reel
DDTC144GUA-7-F	SOT-323	3000/Tape & Reel
DDTC115GUA-7-F	SOT-323	3000/Tape & Reel

Notes: 5. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



XXX = Product Type Marking Code, See Table on Page 1

YM = Date Code Marking Y = Year ex: T = 2006 M = Month ex: 9 = September

Date Code Key

Year	200	16	2007		2008		2009			2011	2	2012	
Code	Т		U		V W		W X			Υ		Z	
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec	
Code	1	2	3	4	5	6	7	8	9	0	N	D	

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